

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

2SA1934

High-Current Switching Applications

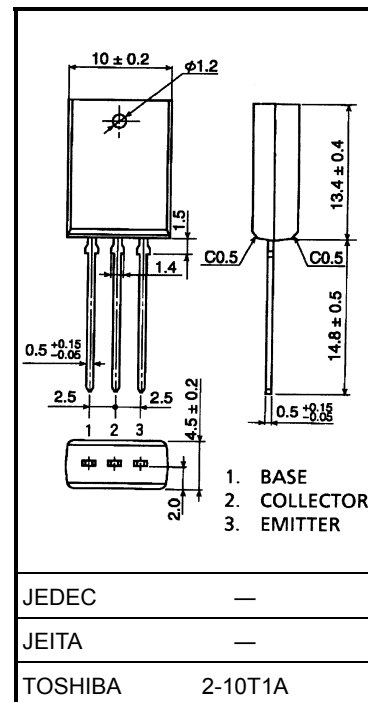
DC-DC Converter Applications

Unit: mm

- Low collector saturation voltage: $V_{CE(sat)} = -0.4 \text{ V (max)} (I_C = -3 \text{ A})$
- High-speed switching: $t_{stg} = 1.0 \text{ } \mu\text{s (typ.)}$
- Complementary to 2SC5176

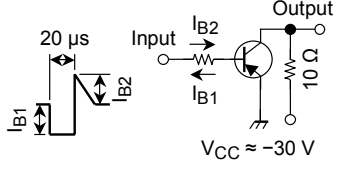
Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	-100	V
Collector-emitter voltage		V_{CEO}	-80	V
Emitter-base voltage		V_{EBO}	-7	V
Collector current	DC	I_C	-5	A
	Pulse	I_{CP}	-8	
Base current		I_B	-1	A
Collector power dissipation		P_C	1.8	W
Junction temperature		T_j	150	$^\circ\text{C}$
Storage temperature range		T_{stg}	-55 to 150	$^\circ\text{C}$



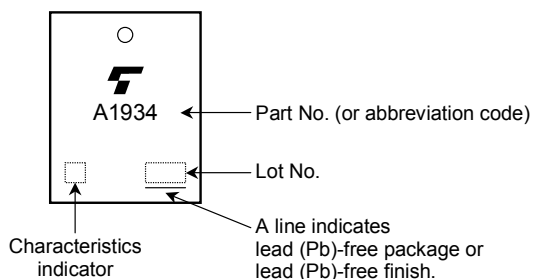
Weight: 1.5 g (typ.)

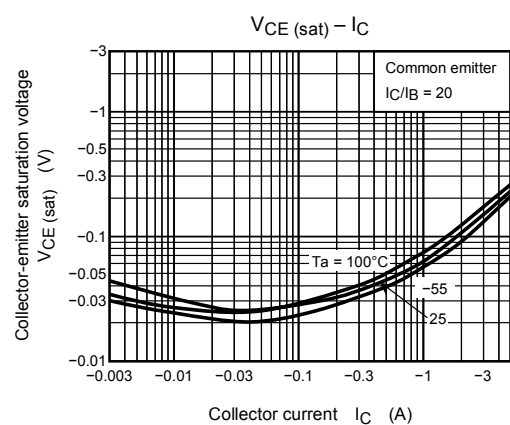
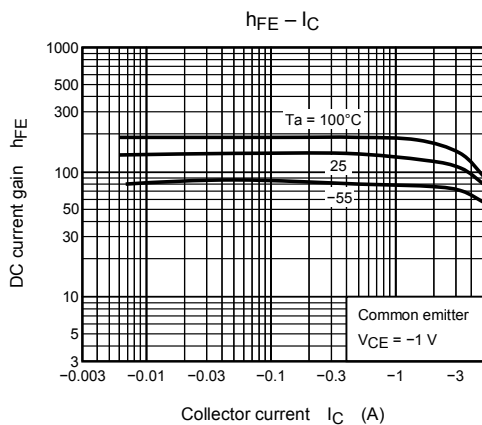
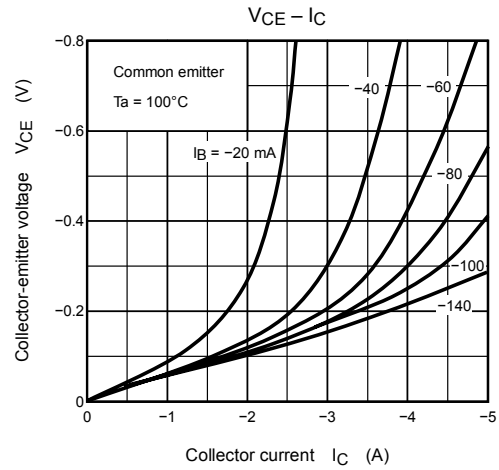
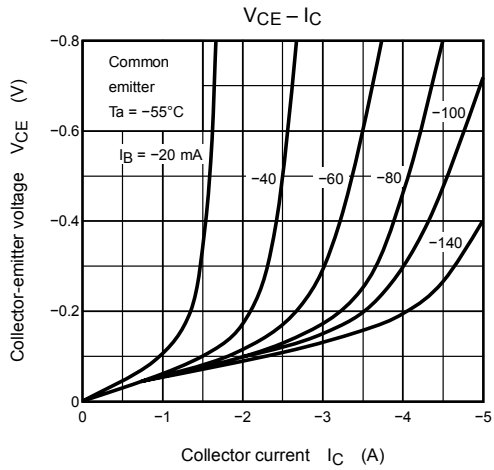
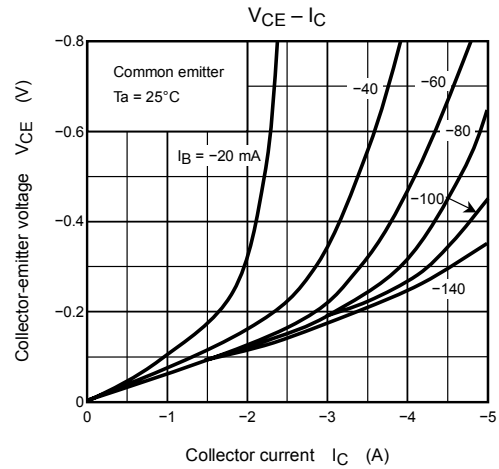
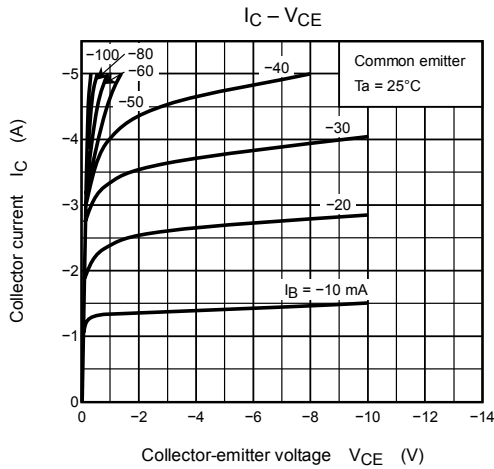
Electrical Characteristics (Ta = 25°C)

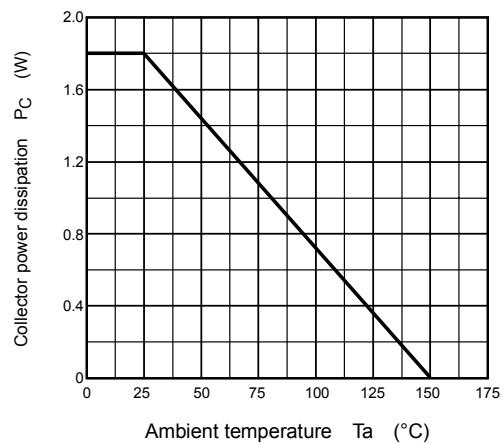
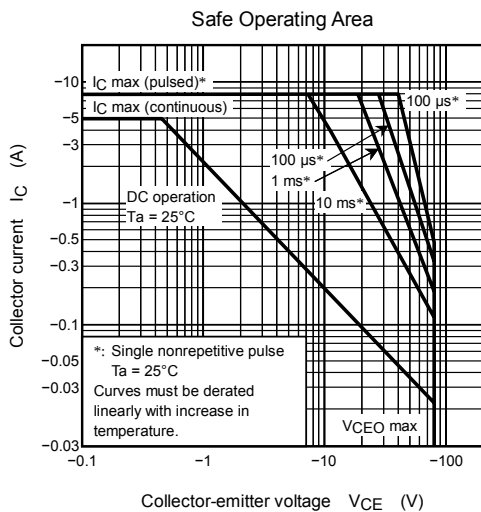
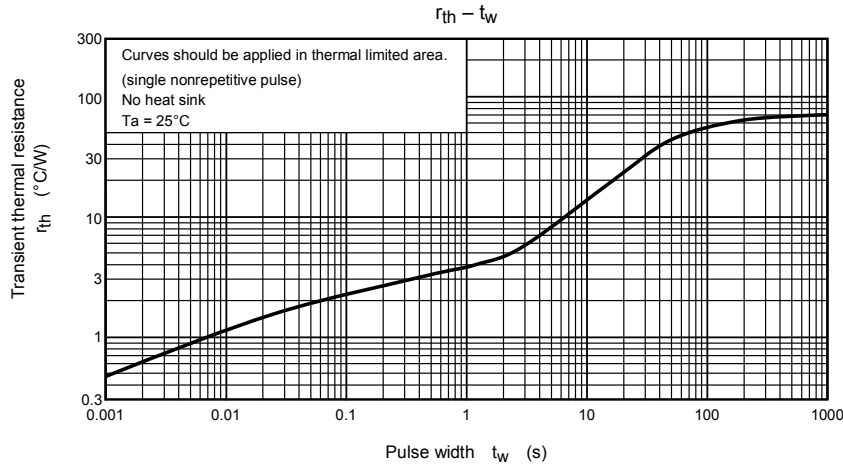
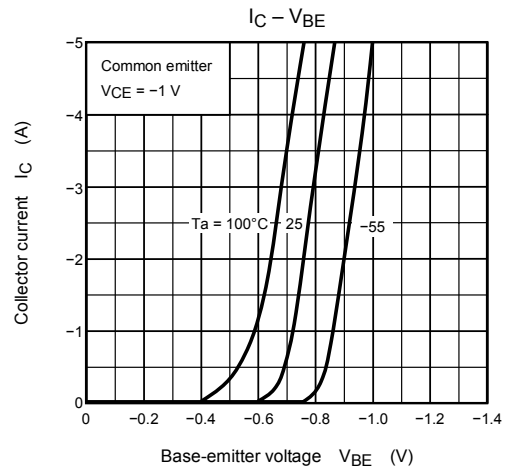
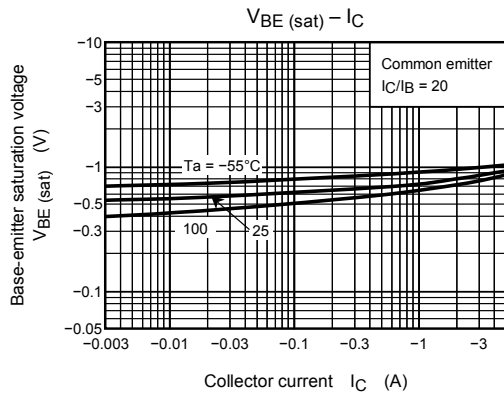
Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current		I_{CBO}	$V_{CB} = -100\text{ V}, I_E = 0$	—	—	-1	μA
Emitter cut-off current		I_{EBO}	$V_{EB} = -7\text{ V}, I_C = 0$	—	—	-1	μA
Collector-emitter breakdown voltage		$V_{(BR)CEO}$	$I_C = -10\text{ mA}, I_B = 0$	-80	—	—	V
DC current gain	$h_{FE(1)}$ (Note)		$V_{CE} = -1\text{ V}, I_C = -1\text{ A}$	70	—	240	
	$h_{FE(2)}$		$V_{CE} = -1\text{ V}, I_C = -3\text{ A}$	40	—	—	
Collector-emitter saturation voltage		$V_{CE(sat)}$	$I_C = -3\text{ A}, I_B = -0.15\text{ A}$	—	-0.2	-0.4	V
Base-emitter saturation voltage		$V_{BE(sat)}$	$I_C = -3\text{ A}, I_B = -0.15\text{ A}$	—	-0.9	-1.2	V
Transition frequency		f_T	$V_{CE} = -4\text{ V}, I_C = -1\text{ A}$	—	60	—	MHz
Collector output capacitance		C_{ob}	$V_{CB} = -10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	200	—	pF
Switching time	Turn-on time	t_{on}	 $-I_{B1} = I_{B2} = 0.15\text{ A}, \text{ duty cycle} \leq 1\%$	—	0.2	—	μs
	Storage time	t_{stg}		—	1.0	—	
	Fall time	t_f		—	0.1	—	

Note: $h_{FE(1)}$ classification O: 70 to 140, Y: 120 to 240

Marking







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